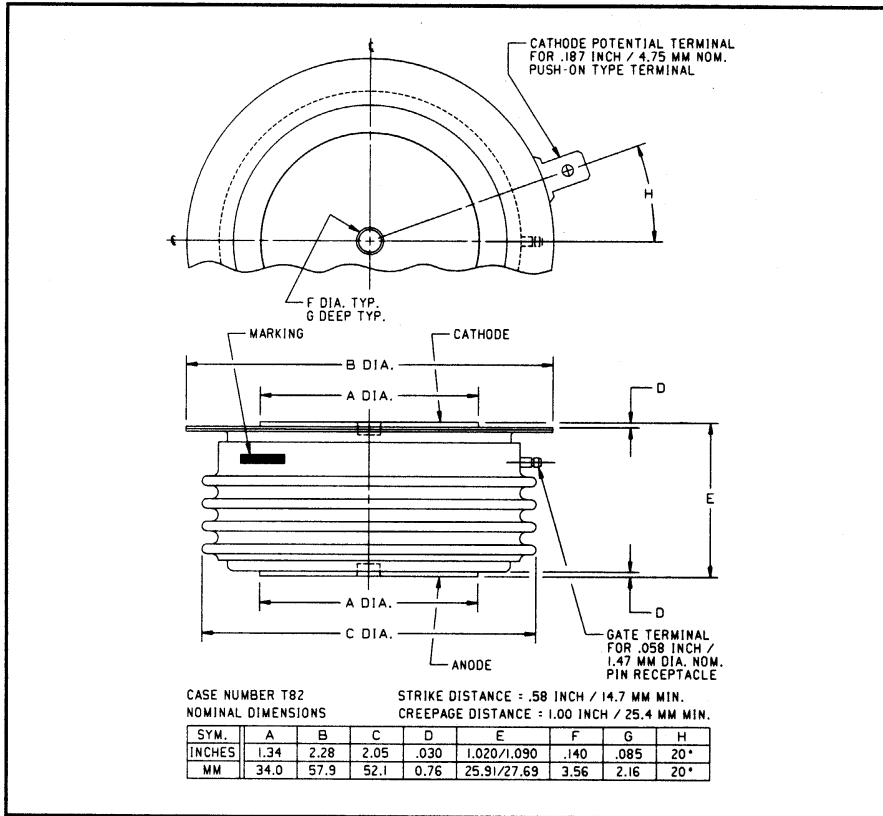


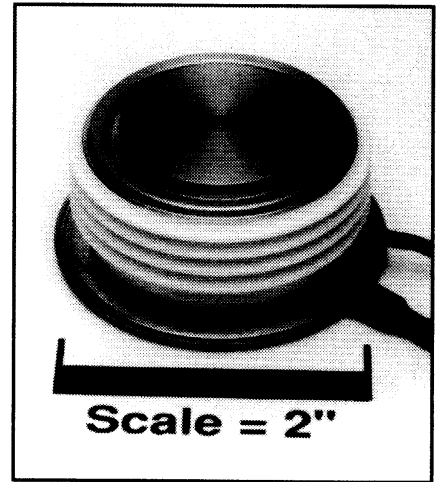
Powerex, Inc., 200 Hillis Street, Youngwood, Pennsylvania 15697-1800 (412) 925-7272
 Powerex, Europe, S.A. 428 Avenue G. Durand, BP107, 72003 Le Mans, France (43) 41.14.14

Phase Control SCR

900 Amperes Average
 1600 Volts



T820 900A (Outline Drawing)



T820 900A Phase Control SCR
 900 Amperes Average, 1600 Volts

Ordering Information:

Select the complete 12 digit part number you desire from the table below.

Type	Voltage	Current	Turn-off	Gate Current	Lead Code
	V_{DRM}/V_{RRM} (Volts)	$I_{T(av)}$ (A)	t_q (μ sec)	I_{GT} (mA)	
T820	02 through 16	90	0	4	DH
	200V through 1600V	900A	200 μ sec (Typical)	150mA	12"

Description:

Powerex Silicon Controlled Rectifiers (SCR) are designed for phase control applications. These are all-diffused, Press-Pak, hermetic Pow-R-Disc devices employing the field proven amplifying gate.

Features:

- Low On-State Voltage
- High di/dt Capability
- High dv/dt Capability
- Hermetic Packaging
- Excellent Surge and I^2t Ratings

Applications:

- Power Supplies
- Motor Control

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T820 900A
Phase Control SCR
 900 Amperes Average, 1600 Volts

Absolute Maximum Ratings

Characteristics	Symbol	T820 900A	Units
Non-repetitive Transient Peak Reverse Voltage	V_{RSM}	$V_{RRM} + 100V$	Volts
RMS On-state Current, $T_C = 70^\circ C$	$I_{T(rms)}$	1410	Amperes
Average Current 180° Sine Wave, $T_C = 70^\circ C$	$I_{T(av)}$	900	Amperes
RMS On-state Current, $T_C = 55^\circ C$	$I_{T(rms)}$	1725	Amperes
Average Current 180° Sine Wave, $T_C = 55^\circ C$	$I_{T(av)}$	1100	Amperes
Peak One Cycle Surge On-state Current (Non-repetitive) 60Hz	I_{tsm}	15000	Amperes
Peak One Cycle Surge On-state Current (Non-repetitive) 50Hz	I_{tsm}	13700	Amperes
Critical Rate-of-rise of On-state Current (Non-repetitive)	di/dt	400	A/ μ sec
Critical Rate-of-rise of On-state Current (Repetitive)	di/dt	150	A/ μ sec
I^2t (for Fusing) for One Cycle, 60Hz	I^2t	935,000	A ² sec
Peak Gate Power Dissipation	P_{GM}	16	Watts
Average Gate Power Dissipation	$P_{G(av)}$	3	Watts
Operating Temperature	T_j	-40 to +125°C	°C
Storage Temperature	T_{stg}	-40 to +150°C	°C
Approximate Weight		8	oz.
		227	g
Mounting Force		3000 to 3500	lb.
		1360 to 1590	kg.



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T820 900A

Phase Control SCR

900 Amperes Average, 1600 Volts

Electrical Characteristics, $T_j = 25^\circ\text{C}$ Unless Otherwise Specified

Characteristics	Symbol	Test Conditions	Min.	Typ.	Max.	Units
Repetitive Peak Reverse Leakage Current	I_{RRM}	$T_j = 125^\circ\text{C}, V_R = V_{RRM}$			35	mA
Repetitive Peak Forward Leakage Current	I_{DRM}	$T_j = 125^\circ\text{C}, V_D = V_{DRM}$			35	mA
Peak On-state Voltage	V_{TM}	$I_{TM} = 1500\text{A Peak}$ Duty Cycle < 0.1%			1.35	Volts
Threshold Voltage, Low-level	$V_{(TO)1}$	$T_j = 125^\circ\text{C}, I = 15\%, I_{T(av)}$ to $\pi I_{T(av)}$			0.78526	Volts
Slope Resistance, Low-level	r_{T1}				0.3505	m Ω
Threshold Voltage, High-level	$V_{(TO)2}$	$T_j = 125^\circ\text{C}, I = \pi I_{T(av)}$ to I_{TSM}			1.0789	Volts
Slope Resistance, High-level	r_{T2}				0.2311	m Ω
V_{TM} Coefficients, Low-level		$T_j = 125^\circ\text{C}, I = 15\% I_{T(av)}$ to $\pi I_{T(av)}$				
					$A_1 = 0.68865$	
					$B_1 = -0.04011$	
					$C_1 = -1.578\text{E-}05$	
					$D_1 = 0.025339$	
V_{TM} Coefficients, High-level		$T_j = 125^\circ\text{C}, I = \pi I_{T(av)}$ to I_{TSM}				
					$A_2 = 2.6289$	
					$B_2 = -0.37766$	
					$C_2 = 8.873\text{E-}05$	
					$D_2 = 0.034055$	
Typical Turn-on Time	t_{on}	$I_T = 1000\text{A}, V_D = 600\text{V}$		5		μsec
Typical Turn-off Time	t_q	$T_j = 125^\circ\text{C}, I_T = 250\text{A},$ $di_R/dt = 50\text{A}/\mu\text{sec}$ Reapplied $dv/dt = 20\text{V}/\mu\text{sec}$ Linear to 80% V_{DRM}		200		μsec
Minimum Critical dv/dt - Exponential to V_{DRM}	dv/dt	$T_j = 125^\circ\text{C}$	300			V/ μsec
Gate Trigger Current	I_{GT}	$T_j = 25^\circ\text{C}, V_D = 12\text{V}$			150	mA
Gate Trigger Voltage	V_{GT}	$T_j = 25^\circ\text{C}, V_D = 12\text{V}$			3.0	Volts
Non-Triggering Gate Voltage	V_{GDM}	$T_j = 125^\circ\text{C}, V_D = V_{DRM}$			0.15	Volts
Peak Forward Gate Current	I_{GTM}				4	A
Peak Reverse Gate Voltage	V_{GRM}				5	Volts

Thermal Characteristics

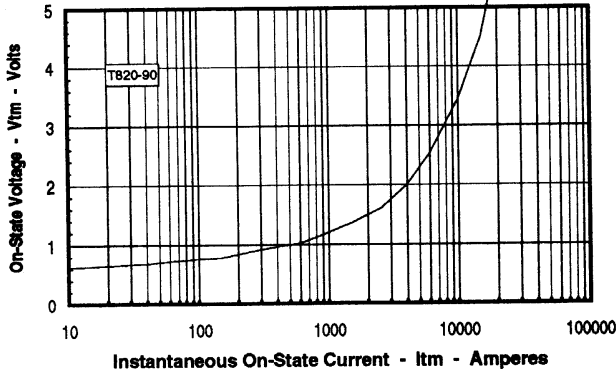
Maximum Thermal Resistance, Double Sided Cooling

Junction-to-Case	$R_{\theta(j-c)}$		0.037	$^\circ\text{C/W}$
Case-to-Sink	$R_{\theta(c-s)}$		0.020	$^\circ\text{C/W}$

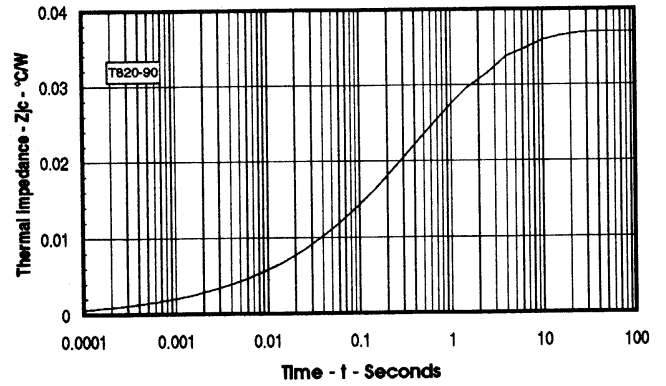
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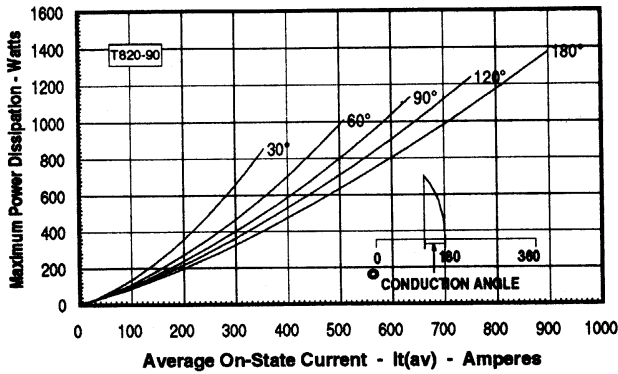
Maximum On-State Forward Voltage Drop
 ($T_j = 125^\circ\text{C}$)



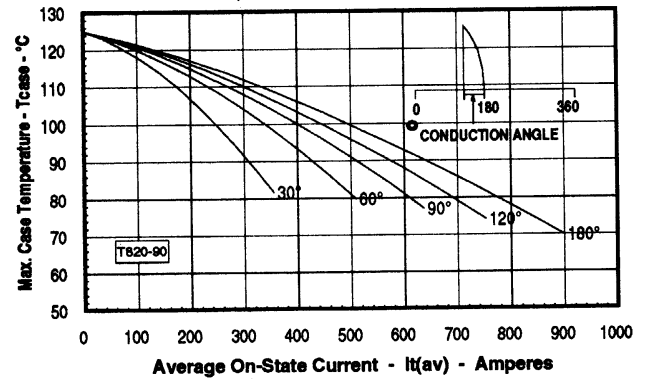
Maximum Transient Thermal Impedance
 (Junction to Case)



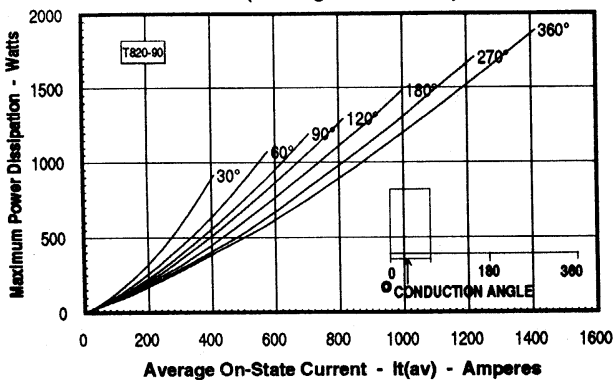
Maximum On-State Power Dissipation
 (Sinusoidal Waveform)



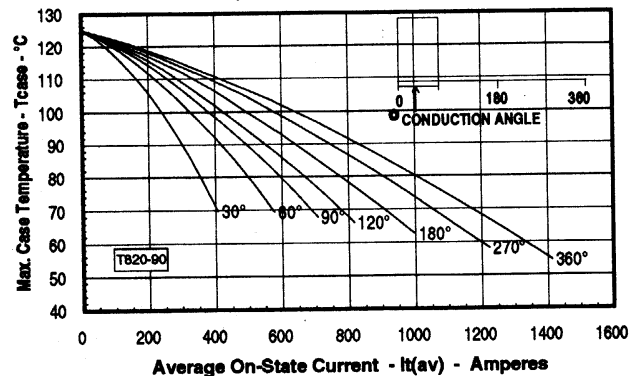
Maximum Allowable Case Temperature
 (Sinusoidal Waveform)



Maximum On-State Power Dissipation
 (Rectangular Waveform)



Maximum Allowable Case Temperature
 (Rectangular Waveform)



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